NSN 5961-01-128-1170

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-128-1170 **Inclosure Material:** Metal **Overall Length:** 1.237 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.430 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 nonrepetitive peak reverse voltage and 30.0 reverse voltage, instantaneous and 30.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 wire hook Shelf Life: N/a **Unit Of Measure: Demilitarization:** No